

# Performance and Reliability of Bonded Interfaces for High-Temperature Packaging















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Project ID: EDT063

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#### **Overview**

#### **Timeline**

- Project Start Date: FY14
- Project End Date: FY17
- Percent Complete: 50%

#### **Budget**

- Total Project Funding: \$1,300K
  - DOE Share: \$1,300K
- **Funding for FY16:** \$400K

#### **Barriers and Targets**

- Cost
- Weight
- Performance and Lifetime

#### **Partners**

- Interactions / Collaborations
  - Oak Ridge National Laboratory (ORNL) (Andrew Wereszczak)
- Project Lead
  - National Renewable Energy Laboratory (NREL)

#### Relevance

- Packaging designs must thermally allow for:
  - High operating temperatures
  - High heat fluxes
  - Hot spots
- Coefficient of thermal expansion (CTE) mismatch between layers of the module will impose stresses that can initiate and propagate defects

CTE  $(x 10^{-6} / K)$ 

Si: 2.6

AIN: 4.5

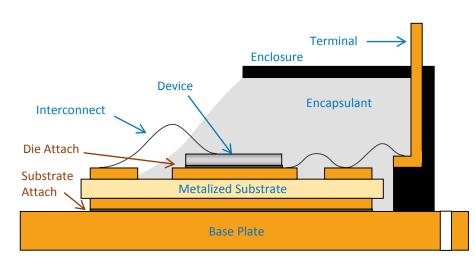
Si<sub>3</sub>N<sub>4</sub>: 3.2

Cu: 16.5

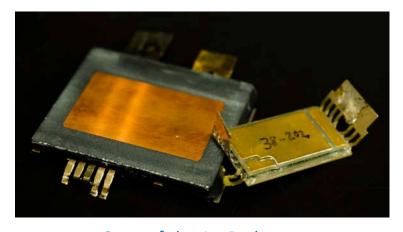
AI: 22.7

Sn<sub>63</sub>Pb<sub>37</sub> Solder: 24.7

Ag: 19.5



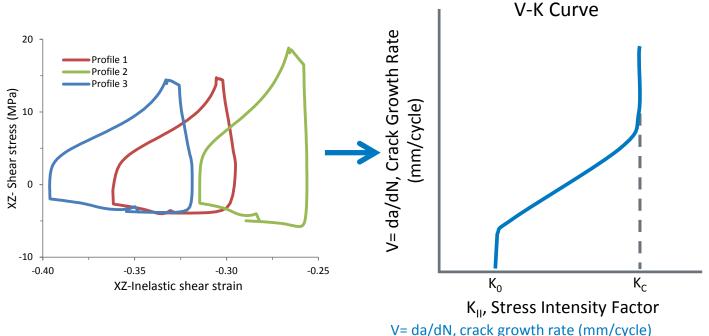
Traditional Power Electronics Package



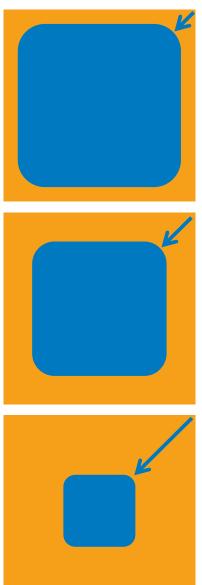
State-of-the-Art Packages

# **Strategy**

- Sintered-silver reliability has not been documented at 200°C conditions for the substrate-attach layer
  - ORNL and NREL's prior experience with sintered-silver processing will generate recommended practices for synthesis of reliable interfaces
- Identify threshold at which stress field is sufficient to cause delamination initiation and measure the resulting crack growth rate



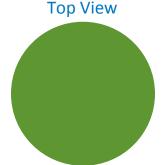
K = stress intensity factor



# **Strategy**

- 1. Process CTE-mismatched disk samples with various diameter bond pads to validate stress field relationship with delamination initiation
  - Subject samples to -40°C to 175°C thermal shock testing
  - Monitor delamination rates through acoustic microscopy





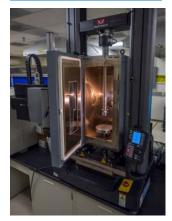
- Synthesize double-lap shear samples for mechanical characterization of sintered-silver
  - Subject samples to shear tests and compare sintered-silver material properties to bulk silver properties
  - Attempt to measure residual stress at room temperature
  - Estimate stress-strain curves
  - Use information to model plastic deformation
- 3. Synthesize Si-Si wafer samples for thermal characterization of bulk and contact resistances



# **Strategy**

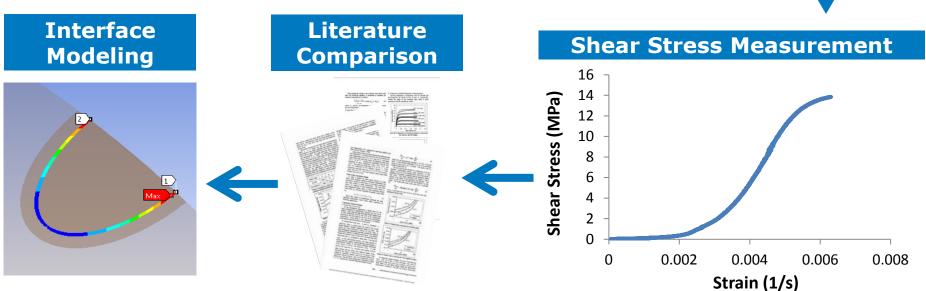
# Sample Synthesis O annie 100 O 5 10 15 20 Time (min)

# **Shear Testing**



25





#### **Milestones**



Perform accelerated life testing and reliability characterization

Model stress field with FEA and develop lifetime model

Process CTE-mismatched disk, shear-stress, and Si-Si wafer samples

Perform additional accelerated life testing, shear testing, and thermal characterization

Go/ No-Go

> Key Deliverable

**Go/No-Go**: Do bonds meet minimum strength requirements?

**Key Deliverable**: Publish stress analysis for sintered-silver

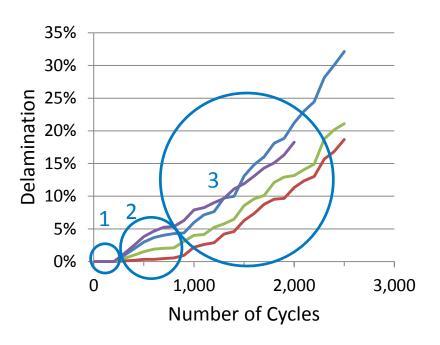
FEA = finite element analysis

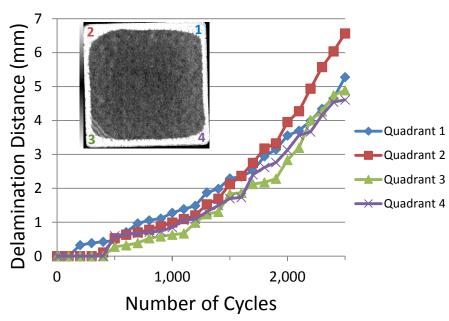
**ORNL** 

**NREL** 

#### **Crack Evaluation**

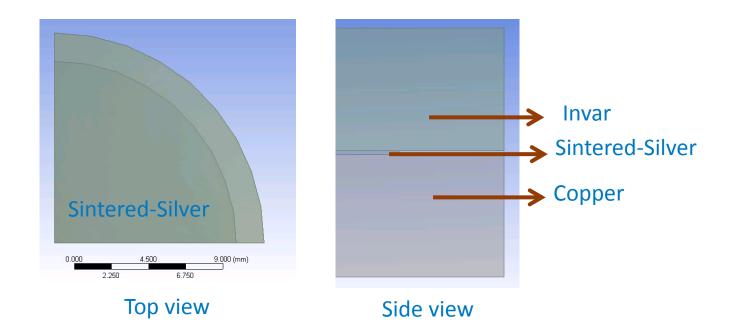
- Identified threshold at which stress field is sufficient to cause delamination initiation
  - Measured delamination rate of 50-mm-x-50-mm sintered-silver samples
    - 1. Identified threshold at which stress intensities are sufficient to cause defect initiation
    - 2. Evaluated the defect region where a transient delamination rate occurs
    - 3. Evaluated the defect region where a constant slope delamination rate occurs
  - Modeled stress field with FEA





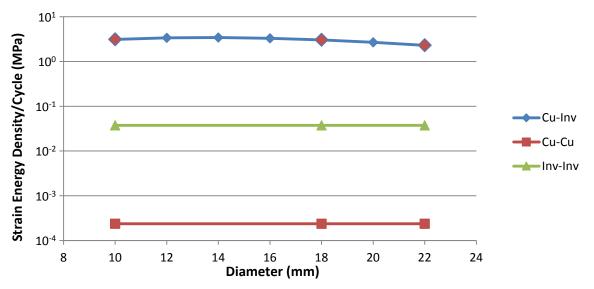
# **Modeling Methodology**

- A fracture mechanics-based approach has been adopted to study the crack growth behavior of sintered-silver under thermal cycling
- A quarter-symmetry model of the round coupon samples was created in ANSYS Workbench
- Strain energy density/cycles results were evaluated



# **Modeling Results**

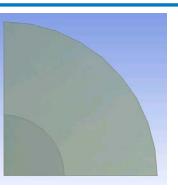
 Evaluated separate simulations with variations in sintered-silver diameter



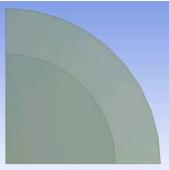
 Cu-Inv simulations generated the highest strain energy density/cycle results

#### **Next Steps**

- J-integral implementation in ANSYS (cyclic versus noncyclic loading
- Crack propagation modeling
- Updated material properties



10 mm



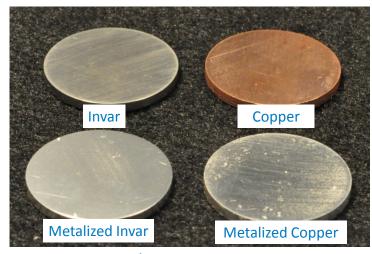
18 mm



22 mm

# **CTE-Mismatched Disk Samples**

- Processed CTE-mismatched disk samples with various diameter bond pads (10 mm, 18 mm, and 22 mm) to validate stress field relationship with delamination initiation
- Invar and copper were selected for round test coupons
  - Coupon dimensions are 25.4 mm in diameter and 2 mm in thickness
  - Surfaces were blanchard ground and metalized with silver
- Process conditions
  - Loctite Ablestik SSP 2020 (Henkel) silver paste was stencil printed to bottom coupon
  - O Dried at 100°C in nitrogen for 2 hours, then top coupon applied
  - O Sintered at 250°C for 1 hour at a pressure of 1 MPa, then cooled while under pressure



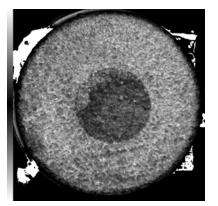
**Invar and Copper Test Coupons** 

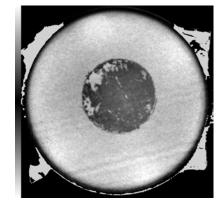


Sample Sintering Assembly

# **CTE-Mismatched Disk Samples**

- Samples have reached 1,700 cycles
  - Cu-Invar samples failed after 100-400 cycles
  - No additional samples have failed after initial delaminations





Scan through 10 mm Cu (left) and Invar (right)

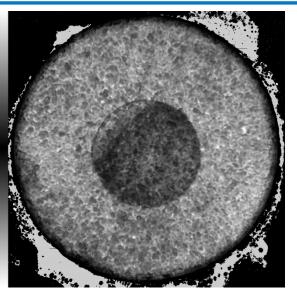




22 mm Cu-Invar sample failure after 100 cycles

Coupons	Stencil	Cycles					
	Diameter (mm)	0	100	200	300	400	1,700
Cu-Cu	10						
							<u> </u>
Invar-Invar							
Cu-Invar							
Cu-Cu	18						
Invar-Invar							
Cu-Invar							
Cu-Cu	22						
Invar-Invar							
Cu-Invar							

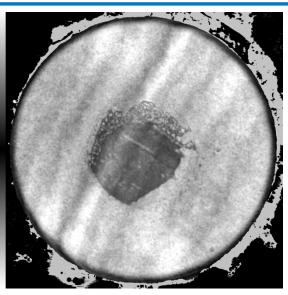
# **CTE-Mismatched Disk Samples**



Copper, 10 mm



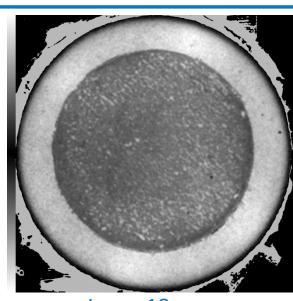
Copper, 10 mm, Processed



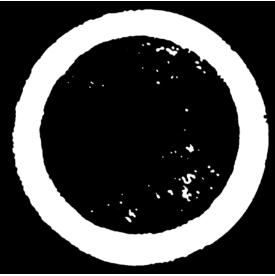
Invar, 10 mm



Invar, 10 mm, Processed



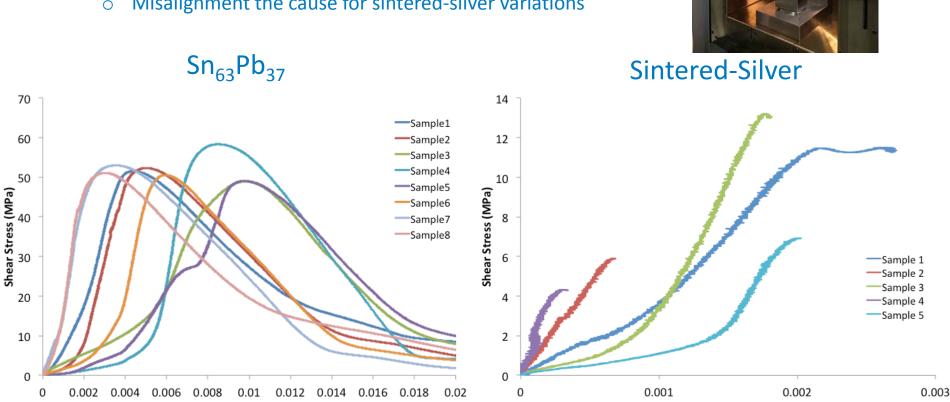
Invar, 18 mm



Invar, 18 mm, Processed

# **Double-Lap Shear Samples**

- Sintered-silver samples exhibited minimal creep during shear testing and lower shear strength than solder samples
- Completed shear fixture modification to allow an additional pivot point to aid in alignment
  - Misalignment the cause for sintered-silver variations

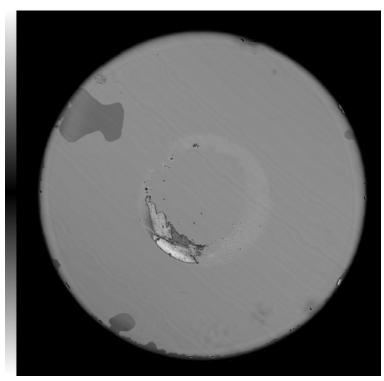


Shear Strain

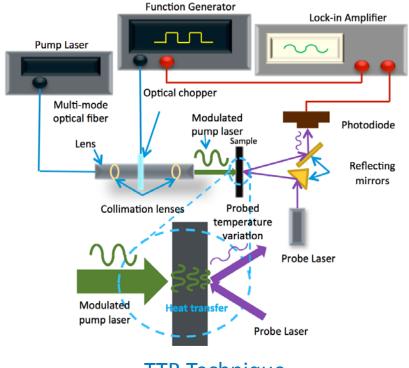
**Shear Strain** 

# Si-Si Bonded Samples

- Prior Si/Al samples were bonded via small section on Si side
  - Si-Si samples will attempt to minimize CTE mismatch and delamination
  - Thermal resistance will be measured via the phase-sensitive transient thermoreflectance (TTR) technique



Partial Si to Sintered-Silver Bond



TTR Technique

#### Responses to Previous Year Reviewers' Comments

The reviewer considered the future work to well defined, but recommended that when looking at bond pad geometries to reduce stress, the project team should also add to the geometries how they may affect the thermal performance.

It is desirable to optimize the CTE mismatch with the package thermal resistance.

This reviewer relayed that modeling updates are progressing, but wondered if a biased humidity test could be included with the thermal cycle tests to determine if the silver material will survive in a typical automotive environment (e.g., no dendrite).

Additional testing procedures will be considered.

### **Collaboration and Coordination**

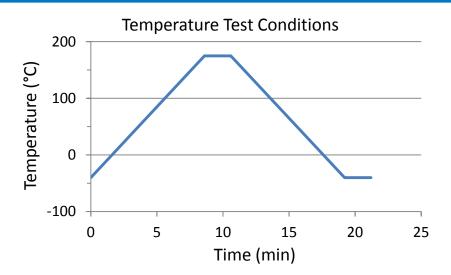
• ORNL: technical partner on sintered-silver samples

# **Remaining Challenges and Barriers**

- Quality of sintered-silver joints is dependent on many parameters (temperature, pressure, time of synthesis, and plating quality)
- Obtaining accurate material properties for sinteredsilver is critical for crack analysis modeling
- Fracture-mechanics-based crack modeling must replicate sintered-silver failure mechanism

# **Proposed Future Work (FY16)**

- Subject additional round samples to accelerated temperature testing:
  - −40°C to 175°C thermal cycle
- Monitor delamination rates through acoustic microscopy
- Synthesize and shear test additional samples for mechanical characterization of sintered-silver
  - Establish lifetime estimation model for sintered-silver
- Synthesize Si-Si bonded sintered-silver samples for characterization of thermal resistance via the TTR technique





Shear Test Fixture and Sample

# **Proposed Future Work (FY17)**

#### Additional Shear Testing

 Additional coupons will be needed for evaluating properties under various temperatures and strain rates

#### Large Area Attach

- Previous substrate-attach evaluations with solders, thermoplastics, and sintered-silvers have utilized 50 mm x 50 mm Si<sub>3</sub>N<sub>4</sub> substrates attached to 50 mm x 50 mm x 5 mm Cu baseplates
- Additional samples will evaluate variations in stencil patterns and plating options

#### Package Integration

 Demonstration of an ORNL double-sided planar package utilizing sintered-silver at die-and substrate-attach layers will be a key milestone for this project







# **Summary**

#### DOE Mission Support:

 Bonded interface materials are a key enabling technology for compact, lightweight, low-cost, reliable packaging, and for high-temperature coolant and air-cooling technical pathways

#### Approach:

 Synthesis of sintered-silver bonds, accelerated temperature cycling, bond inspection (acoustic microscope), and stress field versus cycles-to-failure models

#### Accomplishments:

Characterized the degradation of sintered-silver interfaces

#### Collaborations

o ORNL



#### **Acknowledgments:**

Susan Rogers and Steven Boyd U.S. Department of Energy

#### **Team Members:**

Paul Paret
Andrew Wereszczak\* (ORNL)

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<sup>\*</sup> Jointly funded by the OVT EDT and OVT Propulsion Materials Programs